TPS794xx



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ULTRALOW-NOISE, HIGH-PSRR, FAST, RF, 250-mA LOW-DROPOUT LINEAR REGULATORS

FEATURES

- 250-mA Low-Dropout Regulator With Enable
- Available in Fixed and Adjustable (1.2 V to 5.5 V) Versions
- High PSRR (60 dB at 10 kHz)
- Ultralow Noise (32 μVrms, TPS79428)
- Fast Start-Up Time (50 μs)
- Stable With a 2.2-µF Ceramic Capacitor
- Excellent Load/Line Transient Response
- Very Low Dropout Voltage (155 mV at Full Load)
- Available in MSOP-8 and SOT223-6 Packages

APPLICATIONS

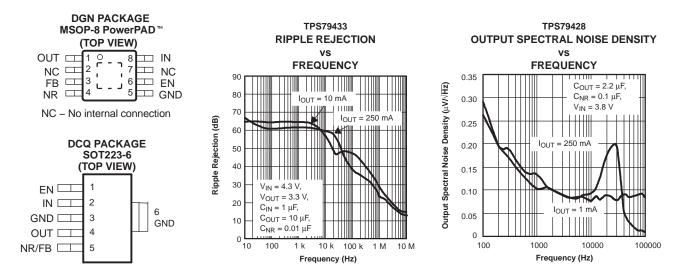
- RF: VCOs, Receivers, ADCs
- Audio

 $\overline{\mathbf{M}}$

- Bluetooth[™], Wireless LAN
- Cellular and Cordless Telephones
- Handheld Organizers, PDAs

DESCRIPTION

The TPS794xx family of low-dropout (LDO) linear voltage regulators features high power-supply rejection ratio (PSRR), ultralow-noise, fast start-up, and excellent line and load transient responses in small outline, MSOP-8 PowerPAD[™] and SOT223-6 packages. Each device in the family is stable with a small 2.2-µF ceramic capacitor on the output. The family uses an advanced, proprietary BiCMOS fabrication process to yield extremely low dropout voltages (for example, 155 mV at 250 mA). Each device achieves fast start-up times (approximately 50 μ s with a 0.001- μ F bypass capacitor) while consuming low quiescent current (170 µA typical). Moreover, when the device is placed in standby mode, the supply current is reduced to less than µA. The TPS79428 exhibits approximately 32 μV_{RMS} of output voltage noise at 2.8 V output with a 0.1-µF bypass capacitor. Applications with analog components that are noise-sensitive, such as portable RF electronics, benefit from the high PSRR and low noise features as well as the fast response time.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾

PRODUCT	V _{OUT} ⁽²⁾
	 XX is nominal output voltage (for example, 28 = 2.8 V, 285 = 2.85 V, 01 = Adjustable). YYY is package designator. Z is package quantity.

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) Output voltages from 1.3 V to 5.0 V in 100 mV increments are available; minimum order quantities may apply. Contact factory for details and availability.

ABSOLUTE MAXIMUM RATINGS

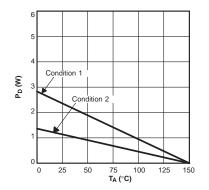
over operating temperature range unless otherwise noted⁽¹⁾

	VALUE
V _{IN} range	–0.3 V to 6 V
V _{EN} range	–0.3 V to V _{IN} + 0.3 V
V _{OUT} range	–0.3 V to 6 V
Peak output current	Internally limited
ESD rating, HBM	2 kV
ESD rating, CDM	500 V
Continuous total power dissipation	See Dissipation Ratings Table
Junction temperature range, T _J	-40°C to +150°C
Storage temperature range, T _{stg}	−65°C to +150°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

PACKAGE DISSIPATION RATINGS

PACKAGE	AIR FLOW (CFM)	R _{θJC} (°C/W)	R _{θJA} (°C/W)	T _A ≤ 25°C POWER RATING	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
	0	8.47	55.09	2.27 W	1.45 W	1.18 W
DGN	150	8.21	49.97	2.50 W	1.60 W	1.30 W
	250	8.20	48.10	2.60 W	1.66 W	1.35 W



CONDITIONS	PACKAGE	PCB AREA	θ JA
1	SOT223	4in ² Top Side Only	53°C/W
2	SOT223	0.5in ² Top Side Only	110°C/W

Figure 1. SOT223 Power Dissipation

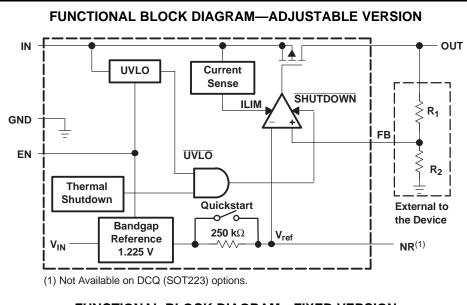
ELECTRICAL CHARACTERISTICS

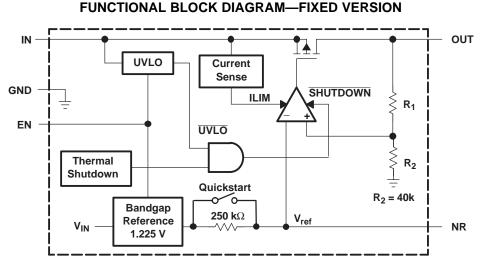
Over recommended operating temperature range ($T_J = -40^{\circ}C$ to 125°C), $V_{EN} = V_{IN}$, $V_{IN} = V_{OUT(nom)} + 1 V^{(1)}$, $I_{OUT} = 1mA$, $C_{OUT} = 10\mu$ F, $C_{NR} = 0.01 \mu$ F, unless otherwise noted. Typical values are at 25°C.

	PARAMETER	DITIONS	MIN	TYP	MAX	UNIT			
Input voltage, V _{IN} ⁽¹⁾				2.7		5.5	V		
Continuous of	tinuous output current, I _{OUT}				0		250	mA	
	Output voltage range	TPS79401			1.225		$5.5 - V_{DO}$	V	
Output voltage	A	TPS79401 ⁽²⁾	$0 \ \mu A \le I_{OUT} \le 250 \ mA, \ V_{OUT}$	+ 1 V \leq V _{IN} \leq 5.5 V ⁽¹⁾	0.97(V _{OUT})	V _{OUT}	1.03(V _{OUT})	V	
voltago	Accuracy	Fixed V _{OUT}	$0 \ \mu A \le I_{OUT} \le 250 \ mA, \ V_{OUT}$	+ 1 V \leq V _{IN} \leq 5.5 V ⁽¹⁾	-3.0		+3.0	%	
Output voltage	ge line regulation (ΔV _{OUT} %			0.12	%/V				
Load regulat	ion (ΔV _{OUT} %/ΔI _{OUT})		$0 \ \mu A \le I_{OUT} \le 250 \ mA$			10		mV	
TPS79428		TPS79428	I _{OUT} = 250 mA			155	210		
	tput current limit ound pin current	TPS79430	I _{OUT} = 250 mA		155	210	mV		
	Sm) Oli V	TPS79433	I _{OUT} = 250 mA	$\begin{array}{c c c c c c c c } 0 & 250 \\ \hline 1.225 & 5.5 - V_{DO} \\ \hline 1.225 & 5.5 - V_{DO} \\ \hline 1.225 & 5.5 - V_{DO} \\ \hline V \leq V_{IN} \leq 250 \text{ mA}, V_{OUT} + 1 \text{ V} \leq V_{IN} \leq 5.5 \text{ V}^{(1)} & -3.0 & +3.0 \\ \hline V \leq V_{IN} \leq 5.5 \text{ V} & 0.05 & 0.12 \\ \hline V \leq V_{IN} \leq 5.5 \text{ V} & 0.05 & 0.12 \\ \hline U_{IT} \leq 250 \text{ mA} & 10 & & & & & & & & & & & & & & & & & $					
Output curre	nt limit		V _{OUT} = 0 V			925		mA	
Ground pin o	current		$0 \ \mu A \le I_{OUT} \le 250 \ mA$			170	220	μΑ	
Shutdown current ⁽⁴⁾			$V_{EN} = 0 \text{ V}, 2.7 \text{ V} \le V_{IN} \le 5.5 \text{ V}$		0.07	1	μA		
FB pin curre	B pin current		V _{FB} = 1.225 V				1	μA	
Power-supply ripple rejection TPS79			f = 100 Hz, I _{OUT} = 250 mA		65				
		TPS79428	f = 10 kHz, I _{OUT} = 250 mA		60		dB		
			f = 100 kHz, I _{OUT} = 250 mA			40			
				$C_{NR} = 0.001 \ \mu F$		55			
	Power-supply ripple rejection Dutput noise voltage	TDC70400	BW = 100 Hz to 100 kHz,	$C_{NR} = 0.0047 \ \mu F$		36			
Output noise	vollage	1F3/9420	I _{OUT} = 250 mA	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	33		μV_{RMS}		
	$\begin{array}{ c c c c c } \hline Prive V_{DUT} & Prive V_{DUT} & 0 \ \mu A \leq \hline Fixed V_{OUT} & 0 \ \mu A \leq \hline Fixed V_{OUT} & 0 \ \mu A \leq \hline Fixed V_{OUT} & 0 \ \mu A \leq \hline Fixed V_{OUT} & 0 \ \mu A \leq \hline Fixed V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OUT} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \leq \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu A \in \hline Prive V_{OU} & 0 \ \mu$		$C_{NR} = 0.1 \ \mu F$		32				
				$C_{NR} = 0.001 \ \mu F$		50			
Time, start-u	p	TPS79428	R_L = 14 Ω , C_{OUT} = 1 μ F	$C_{NR} = 0.0047 \ \mu F$		70		μs	
				$C_{NR} = 0.01 \ \mu F$		100			
High-level er	nable input voltage		$2.7~\text{V} \leq \text{V}_{\text{IN}} \leq 5.5~\text{V}$		1.7		V _{IN}	V	
Low-level en	able input voltage		$2.7~\text{V} \leq \text{V}_{\text{IN}} \leq 5.5~\text{V}$		0		0.7	V	
EN pin curre	nt		V _{EN} = 0		1		1	μΑ	
UVLO thresh	nold		V _{CC} rising		2.25		2.65	V	
UVLO hyste	resis					100		mV	



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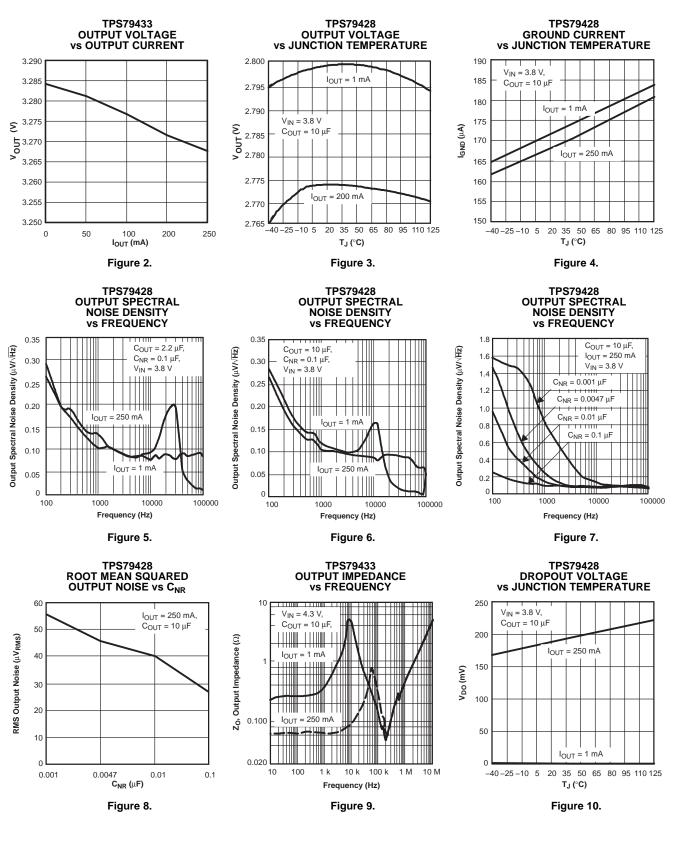
Terminal Functions

	TERMINA	L	
NAME	DGN (MSOP)	DCQ (SOT223)	DESCRIPTION
NR	4	5	Connecting an external capacitor to this pin bypasses noise generated by the internal bandgap, which improves power-supply rejection and reduces output noise.
EN	6	1	The EN terminal is an input that enables or shuts down the device. When EN is a logic high, the device is enabled. When the device is a logic low, the device is in shutdown mode.
FB	3	5	Feedback input voltage for the adjustable device.
GND	5, PAD	3, 6	Regulator ground
IN	8	2	Unregulated input to the device.
NC	2, 7		No internal connection.
OUT	1	4	Regulator output

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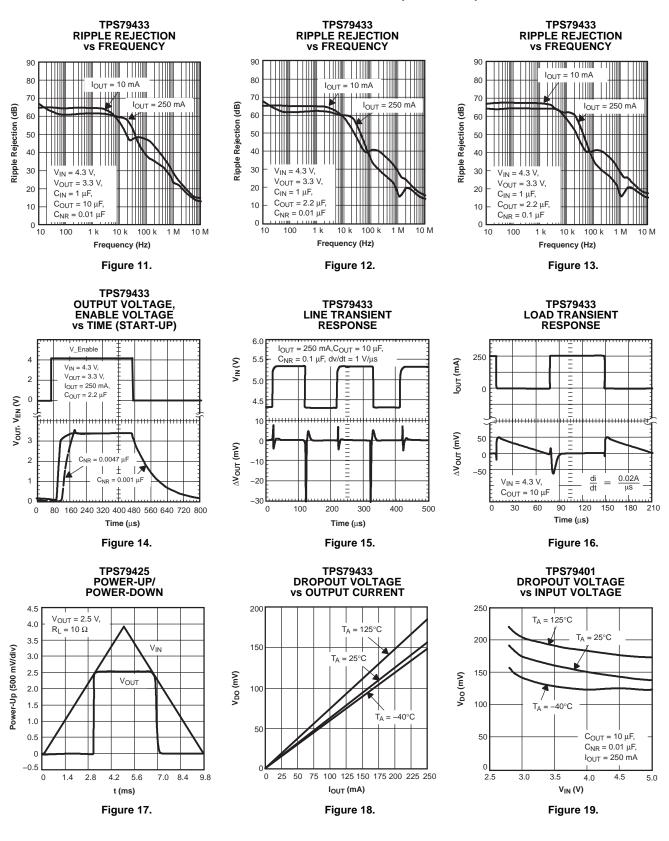
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TYPICAL CHARACTERISTICS



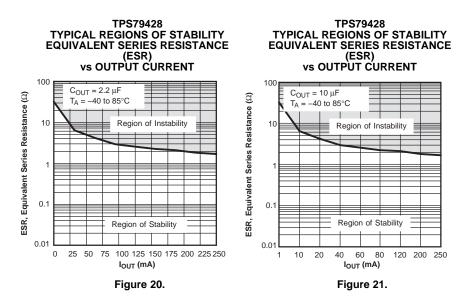
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TYPICAL CHARACTERISTICS (continued)



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TYPICAL CHARACTERISTICS (continued)





APPLICATION INFORMATION

The TPS794xx family of low-dropout (LDO) regulators has been optimized for use in noise-sensitive equipment. The device features extremely low dropout voltages, high PSRR, ultralow output noise, low quiescent current (265 μ A typically), and an enable input to reduce supply currents to less than 1 μ A when the regulator is turned off.

A typical application circuit is shown in Figure 22.

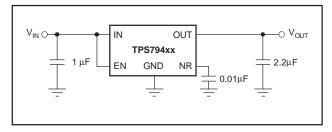


Figure 22. Typical Application Circuit

EXTERNAL CAPACITOR REQUIREMENTS

A $1-\mu F$ or larger ceramic input bypass capacitor, connected between IN and GND and located close to the TPS794xx, is required for stability and improves transient response, noise rejection, and ripple rejection. A higher-value input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

Like most low-dropout regulators, the TPS794xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance is 1 $\mu F.$ Any

1 μ F or larger ceramic capacitor is suitable.

The internal voltage reference is a key source of noise in an LDO regulator. The TPS794xx has an NR pin which is connected to the voltage reference through a 250-k Ω internal resistor. The 250-k Ω internal resistor, in conjunction with an external bypass capacitor connected to the NR pin, creates a low-pass filter to reduce the voltage reference noise and, therefore, the noise at the regulator output. In

order for the regulator to operate properly, the current flow out of the NR pin must be at a minimum, because any leakage current creates an IR drop across the internal resistor, thus creating an output error. Therefore, the bypass capacitor must have minimal leakage current. The bypass capacitor should be no more than $0.1-\mu$ F in order to ensure that it is fully charged during the quickstart time provided by the internal switch shown in the Functional Block Diagram.

For example, the TPS79430 exhibits only 33 μ V_{RMS} of output voltage noise using a 0.1- μ F ceramic bypass capacitor and a 10- μ F ceramic output capacitor. Note that the output starts up slower as the bypass capacitance increases because of the RC time constant at the bypass pin that is created by the internal 250-k Ω resistor and external capacitor.

BOARD LAYOUT RECOMMENDATION TO IMPROVE PSRR AND NOISE PERFORMANCE

To improve ac measurements such as PSRR, output noise, and transient response, it is recommended that the board be designed with separate ground planes for $V_{\rm IN}$ and $V_{\rm OUT}$, with each ground plane connected only at the ground pin of the device. In addition, the ground connection for the bypass capacitor should connect directly to the ground pin of the device.

REGULATOR MOUNTING

The tab of the SOT223-6 package is electrically connected to ground. For best thermal performance, the tab of the surface-mount version should be soldered directly to a circuit-board copper area. Increasing the copper area improves heat dissipation.

Solder pad footprint recommendations for the devices are presented in Application Report SBFA015, Solder Pad Recommendations for Surface-Mount Devices, available from the TI web site (www.ti.com).

PROGRAMMING THE TPS79401 ADJUSTABLE LDO REGULATOR

The output voltage of the TPS79401 adjustable regulator is programmed using an external resistor divider as shown in Figure 23. The output voltage is calculated using Equation 1:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R_1}{R_2}\right)$$
(1)

where:

V_{REF} = 1.2246 V typ (the internal reference voltage)

Resistors R_1 and R_2 should be chosen for approximately 40- μ A divider current. Lower value resistors can be used for improved noise performance, but the device wastes more power. Higher values should be avoided, as leakage current at FB increases the output voltage error.

The recommended design procedure is to choose $R_2 = 30.1 \text{ k}\Omega$ to set the divider current at 40 μ A, $C_1 = 15 \text{ pF}$ for stability, and then calculate R_1 using Equation 2:

$$R_{1} = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R_{2}$$
(2)

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In order to improve the stability of the adjustable version, it is suggested that a small compensation capacitor be placed between OUT and FB.

The approximate value of this capacitor can be calculated as Equation 3:

$$C_{1} = \frac{(3 \times 10^{-7}) \times (R_{1} + R_{2})}{(R_{1} \times R_{2})}$$
(3)

The suggested value of this capacitor for several resistor ratios is shown in the table within Figure 23. If this capacitor is not used (such as in a unity-gain configuration), then the minimum recommended output capacitor is 2.2 μ F instead of 1 μ F.

REGULATOR PROTECTION

The TPS794xx PMOS-pass transistor has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (for example, during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting might be appropriate.

The TPS794xx features internal current limiting and thermal protection. During normal operation, the TPS794xx limits output current to approximately 2.8 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds approximately 165°C, thermal-protection circuitry shuts it down. Once the device has cooled down to below approximately 140°C, regulator operation resumes.

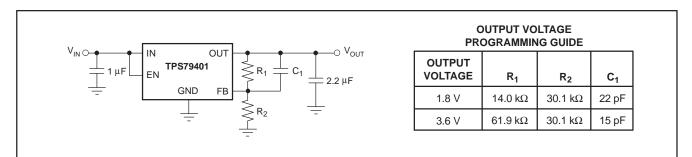


Figure 23. TPS79401 Adjustable LDO Regulator Programming

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THERMAL INFORMATION

The amount of heat that an LDO linear regulator generates is directly proportional to the amount of power it dissipates during operation. All integrated circuits have a maximum allowable junction temperature (T_J max) above which normal operation is not assured. A system designer must design the operating environment so that the operating junction temperature (T_J) does not exceed the maximum junction temperature (T_J max). The two main environmental variables that a designer can use to improve thermal performance are air flow and external heatsinks. The purpose of this information is to aid the designer in determining the proper operating environment for a linear regulator that is operating at a specific power level.

In general, the maximum expected power (P_Dmax) consumed by a linear regulator is computed as shown in Equation 4:

$$P_{D} \max = (V_{IN(avg)} - V_{OUT(avg)}) \times I_{OUT(avg)} + V_{I(avg)} \times I_{Q}$$
(4)

where:

- V_{IN(avg)} is the average input voltage
- V_{OUT(avg)} is the average output voltage
- I_{OUT(avg)} is the average output current
- Io is the quiescent current

For most TI LDO regulators, the quiescent current is insignificant compared to the average output current; therefore, the term $V_{IN(avg)} \ge I_Q$ can be neglected. The operating junction temperature is computed by adding the ambient temperature (T_A) and the increase in temperature due to the regulator's power dissipation. The temperature rise is computed by multiplying the maximum expected power dissipation by the sum of the thermal resistances between the junction and the case ($R_{\Theta JC}$), the case to heatsink $(R_{\Theta CS})$, and the heatsink to ambient $(R_{\Theta SA})$. Thermal resistances are measures of how effectively an object dissipates heat. Typically, the larger the device, the more surface area available for power dissipation and the lower the object's thermal resistance.

Figure 24 illustrates these thermal resistances for a SOT223 package mounted in a JEDEC low-K board.

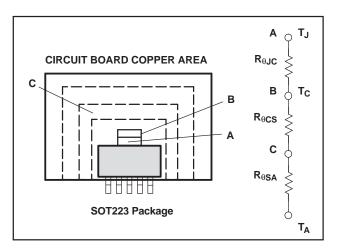


Figure 24. Thermal Resistances

Equation 5 summarizes the computation:

 $T_{J} = T_{A} + P_{D} \max \times (R_{\theta JC} + R_{\theta CS} + R_{\theta SA})$ (5)

The R_{ΘJC} is specific to each regulator as determined by its package, lead frame, and die size provided in the regulator's data sheet. The R_{ΘSA} is a function of the type and size of heatsink. For example, *black body radiator* type heatsinks can have R_{ΘCS} values ranging from 5°C/W for very large heatsinks to 50°C/W for very small heatsinks. The R_{ΘCS} is a function of how the package is attached to the heatsink. For example, if a thermal compound is used to attach a heatsink to a SOT223 package, R_{ΘCS} of 1°C/W is reasonable.

Even if no external black body radiator type heatsink is attached to the package, the board on which the regulator is mounted provides some heatsinking through the pin solder connections. Some packages, like the DDPAK and SOT223 packages, use a copper plane underneath the package or the circuit board ground plane for additional heatsinking to improve their thermal performance. Computer-aided thermal modeling can be used to compute very accurate approximations of an integrated circuit's performance in different operating thermal environments (for example, different types of circuit boards, different types and sizes of heatsinks, different air flows, etc.). Using these models, the three thermal resistances can be combined into one thermal resistance between junction and ambient $(R_{\Theta,JA})$. This $R_{\Theta,JA}$ is valid only for the specific operating environment used in the computer model.

Equation 5 simplifies into Equation 6: $T_J = T_A + P_D \max \times R_{\theta JA}$

Rearranging Equation 6 gives Equation 7:

$$R_{\theta JA} = \frac{T_J - T_A}{P_D \max}$$
(7)

(6)

Using Equation 6 and the computer model generated curves shown in Figure 25, a designer can quickly compute required heatsink thermal the resistance/board area for а given ambient temperature, power dissipation, and operating environment.

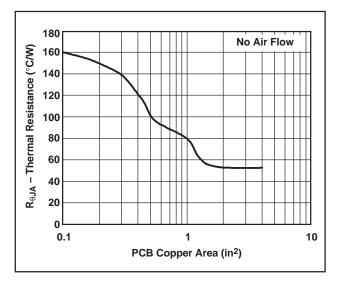


Figure 25. SOT223 Thermal Resistance vs PCB Copper Area

SOT223 POWER DISSIPATION

The SOT223 package provides an effective means of managing power dissipation in surface-mount

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applications. The SOT223 package dimensions are provided in the *Mechanical Data* section at the end of the data sheet. The addition of a copper plane directly underneath the SOT223 package enhances the thermal performance of the package.

To illustrate, the TPS79425 in a SOT223 package was chosen. For this example, the average input voltage is 3.3 V, the output voltage is 2.5 V, the average output current is 1 A, the ambient temperature 55°C, no air flow is present, and the operating environment is the same as documented below. Neglecting the quiescent current, the maximum average power is Equation 8:

$$P_{D}max = (3.3 - 2.5)V \times 1A = 800mW$$
 (8)

Substituting T_J max for T_J into Equation 4 gives Equation 9:

$$R_{\theta JA} \max = (125 - 55)^{\circ}C/800 \,\text{mW} = 87.5^{\circ}C/W$$
(9)

From Figure 25, $R_{\theta JA}$ vs PCB Copper Area, the ground plane needs to be 0.55 in² for the part to dissipate 800 mW. The operating environment used to construct Figure 25 consisted of a board with 1 oz. copper planes. The package is soldered to a 1 oz. copper pad on the top of the board. The pad is tied through thermal vias to the 1 oz. ground plane.

From the data in Figure 25 and rearranging equation 6, the maximum power dissipation for a different ground plane area and a specific ambient temperature can be computed, as shown in Figure 26.

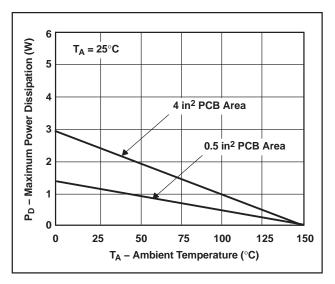


Figure 26. SOT223 Maximum Power Dissipation vs Ambient Temperature



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS79401DCQ	OBSOLETE	SOT-223	DCQ	6		TBD	Call TI	Call TI	-40 to 85	PS79401	
TPS79401DCQR	ACTIVE	SOT-223	DCQ	6	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PS79401	Samples
TPS79401DGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AXL	Samples
TPS79401DGNT	OBSOLETE	HVSSOP	DGN	8		TBD	Call TI	Call TI	-40 to 85	AXL	
TPS79418DCQ	OBSOLETE	SOT-223	DCQ	6		TBD	Call TI	Call TI	-40 to 85	PS79418	
TPS79418DCQR	ACTIVE	SOT-223	DCQ	6	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PS79418	Samples
TPS79418DGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AXM	Samples
TPS79418DGNT	OBSOLETE	HVSSOP	DGN	8		TBD	Call TI	Call TI	-40 to 85	AXM	
TPS79425DCQ	OBSOLETE	SOT-223	DCQ	6		TBD	Call TI	Call TI	-40 to 85	PS79425	
TPS79425DCQR	ACTIVE	SOT-223	DCQ	6	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PS79425	Samples
TPS79425DGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	АҮВ	Samples
TPS79425DGNT	OBSOLETE	HVSSOP	DGN	8		TBD	Call TI	Call TI	-40 to 85	AYB	
TPS79428DCQ	OBSOLETE	SOT-223	DCQ	6		TBD	Call TI	Call TI	-40 to 85	PS79428	
TPS79428DCQR	ACTIVE	SOT-223	DCQ	6	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PS79428	Samples
TPS79428DGNT	ACTIVE	HVSSOP	DGN	8	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AYC	Samples
TPS79430DCQ	ACTIVE	SOT-223	DCQ	6	78	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PS79430	Samples
TPS79430DCQR	ACTIVE	SOT-223	DCQ	6	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PS79430	Samples
TPS79430DGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AYD	Samples
TPS79430DGNT	OBSOLETE	HVSSOP	DGN	8		TBD	Call TI	Call TI	-40 to 85	AYD	
TPS79433DCQ	OBSOLETE	SOT-223	DCQ	6		TBD	Call TI	Call TI	-40 to 85	PS79433	
TPS79433DCQR	ACTIVE	SOT-223	DCQ	6	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PS79433	Samples
TPS79433DGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AYE	Samples
TPS79433DGNT	OBSOLETE	HVSSOP	DGN	8		TBD	Call TI	Call TI	-40 to 85	AYE	

PACKAGE OPTION ADDENDUM



⁽¹⁾ The marketing status values are defined as follows:
 ACTIVE: Product device recommended for new designs.
 LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
 NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
 PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
 OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption. **Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nomina	l				0	L.				r.		t.
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS79401DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.1	7.45	1.88	8.0	12.0	Q3
TPS79418DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.1	7.45	1.88	8.0	12.0	Q3
TPS79418DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS79425DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.1	7.45	1.88	8.0	12.0	Q3
TPS79425DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS79428DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.1	7.45	1.88	8.0	12.0	Q3
TPS79428DGNT	HVSSOP	DGN	8	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS79430DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.1	7.45	1.88	8.0	12.0	Q3
TPS79430DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS79433DCQR	SOT-223	DCQ	6	2500	330.0	12.4	7.1	7.45	1.88	8.0	12.0	Q3
TPS79433DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS79433DGNT	HVSSOP	DGN	8	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

12-Jun-2024



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS79401DCQR	SOT-223	DCQ	6	2500	346.0	346.0	29.0
TPS79418DCQR	SOT-223	DCQ	6	2500	346.0	346.0	41.0
TPS79418DGNR	HVSSOP	DGN	8	2500	356.0	356.0	35.0
TPS79425DCQR	SOT-223	DCQ	6	2500	346.0	346.0	41.0
TPS79425DGNR	HVSSOP	DGN	8	2500	356.0	356.0	35.0
TPS79428DCQR	SOT-223	DCQ	6	2500	358.0	335.0	35.0
TPS79428DGNT	HVSSOP	DGN	8	250	210.0	185.0	35.0
TPS79430DCQR	SOT-223	DCQ	6	2500	346.0	346.0	29.0
TPS79430DGNR	HVSSOP	DGN	8	2500	356.0	356.0	35.0
TPS79433DCQR	SOT-223	DCQ	6	2500	346.0	346.0	29.0
TPS79433DGNR	HVSSOP	DGN	8	2500	356.0	356.0	35.0
TPS79433DGNT	HVSSOP	DGN	8	250	210.0	185.0	35.0

TEXAS INSTRUMENTS

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12-Jun-2024

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
TPS79430DCQ	DCQ	SOT-223	6	78	532.13	8.63	3.6	3.68

GENERIC PACKAGE VIEW

PowerPAD VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

3 x 3, 0.65 mm pitch

DGN 8

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





4225482/A

DGN0008D

PACKAGE OUTLINE

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



DGN0008D

EXAMPLE BOARD LAYOUT

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
- on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



DGN0008D

EXAMPLE STENCIL DESIGN

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.



PACKAGE OUTLINE

DGN0008G

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



PowerPAD is a trademark of Texas Instruments.

DGN0008G

EXAMPLE BOARD LAYOUT

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown
- on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



DGN0008G

EXAMPLE STENCIL DESIGN

PowerPAD[™] VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.



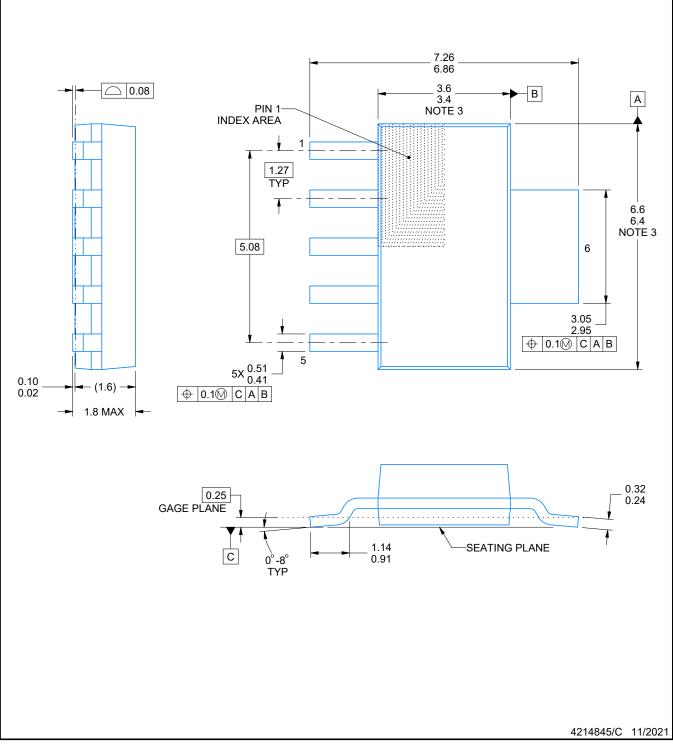
DCQ0006A



PACKAGE OUTLINE

SOT - 1.8 mm max height

PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.

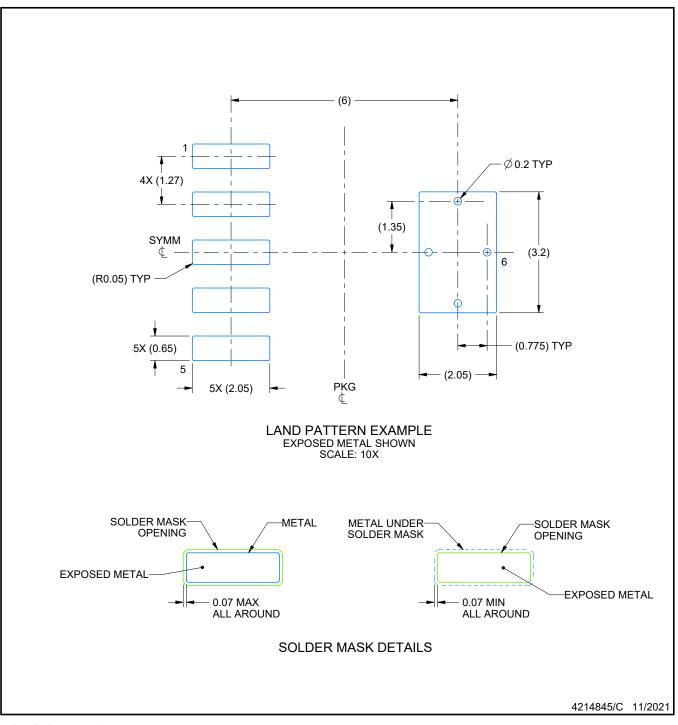


DCQ0006A

EXAMPLE BOARD LAYOUT

SOT - 1.8 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.6. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

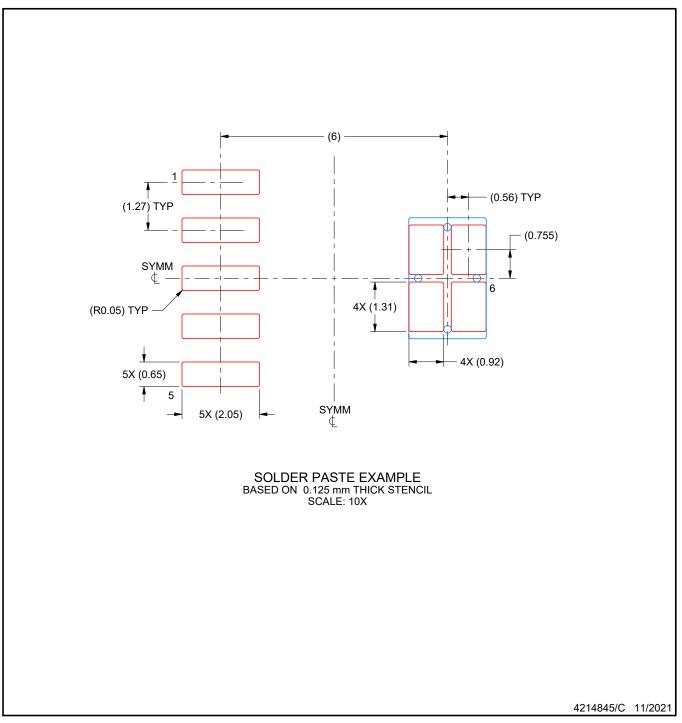


DCQ0006A

EXAMPLE STENCIL DESIGN

SOT - 1.8 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



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